

Data sheet acquired from Harris Semiconductor SCHS168D

CD54HC243, CD74HC243, CD54HCT243

High-Speed CMOS Logic

Quad-Bus Transceiver with Three-State Outputs

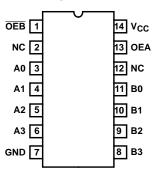
November 1997 - Revised October 2003

Features

- Typical Propagation Delay (A to B, B to A) of 7ns at V_{CC} = 5V, C_L = 15pF, T_A = 25°C
- Three-State Outputs
- Buffered Inputs
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ...-55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL} = 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Pinout

CD54HC243, CD54HCT243 (CERDIP) CD74HC243, CD74HCT243 (PDIP, SOIC) TOP VIEW



Description

The 'HC243 and 'HCT243 silicon-gate CMOS three-state bidirectional noninverting buffers are intended for two-way asynchronous communication between data buses. They have high-drive-current outputs that enable high-speed operation when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuits and have speeds comparable to low-power Schottky TTL circuits. They can drive 15 LSTTL loads.

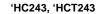
The states of the output-enable ($\overline{\text{OEB}}$, OEA) inputs determine both the direction of flow (A to B, B to A), and the three-state mode.

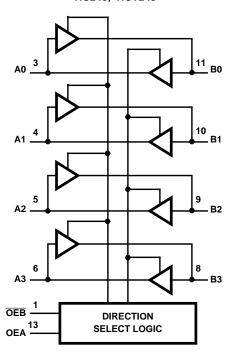
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC243F3A	-55 to 125	14 Ld CERDIP
CD54HCT243F3A	-55 to 125	14 Ld CERDIP
CD74HC243E	-55 to 125	14 Ld PDIP
CD74HC243M	-55 to 125	14 Ld SOIC
CD74HC243MT	-55 to 125	14 Ld SOIC
CD74HC243M96	-55 to 125	14 Ld SOIC
CD74HCT243E	-55 to 125	14 Ld PDIP
CD74HCT243M	-55 to 125	14 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Functional Diagram





TRUTH TABLE

		HC, HCT243 SERIES				
CONTRO	L INPUTS	DATA PORT STATUS				
OEB	OEA	An	Bn			
Н	Н	0	I			
L	Н	Z	Z			
Н	L	Z	Z			
L	L	I	0			

H= High Voltage Level

L= Low Voltage Level

I= Input

O= Output (Same Level as Input)

Z= High Impedance

To prevent excess currents in the High Z modes all I/O terminals should be terminated with 10k Ω to 1M Ω resistors.

CD54HC243, CD74HC243, CD54HCT243, CD74HCT243

Absolute Maximum Ratings DC Supply Voltage, V_{CC}-0.5V to 7V DC Input Diede Current Inc.

DC Input Diode Current, I_{IK} For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$... ± 20 mA DC Output Diode Current, I_{OK} For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$... ± 20 mA

For $V_O > -0.5 V$ or $V_O < V_{CC} + 0.5 V$... $\pm 25 mA$ DC V_{CC} or Ground Current, I_{CC} ... $\pm 70 mA$

Operating Conditions

Temperature Range (T _A)
Supply Voltage Range, V _{CC}
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (°C/W)
E (PDIP) Package	80
M (SOIC) Package	
Maximum Junction Temperature	150 ⁰ C
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS			25°C		-40°C 1	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES			-						-			
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	٧
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	٧
				6	4.2	-	-	4.2	-	4.2	-	٧
Low Level Input	V _{IL}	=	-	2	-	-	0.5	=	0.5	-	0.5	٧
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	٧
				6	-	-	1.8	-	1.8	-	1.8	٧
High Level Output	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	٧
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	٧
			-0.02	6	5.9	-	-	5.9	-	5.9	-	٧
High Level Output			-6	4.5	3.98	-	-	3.84	-	3.7	-	٧
Voltage TTL Loads			-7.8	6	5.48	-	-	5.34	-	5.2	-	٧
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads		VIL	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Voltage TTL Loads			7.8	6	-	-	0.26	-	0.33	-	0.4	V

CD54HC243, CD74HC243, CD54HCT243, CD74HCT243

DC Electrical Specifications (Continued)

			ST ITIONS			25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	v _{cc} (v)	MIN	TYP	МАХ	MIN	MAX	MIN	МАХ	UNITS
Input Leakage Current	II	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ
Three-State Leakage Current	l _{OZ}	V _{IL} or V _{IH}	-	6	-	-	±0.5	-	±0.5	-	±10	μА
HCT TYPES	•									•	•	
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	٧
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	٧
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	٧
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	٧
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	٧
Input Leakage Current	lı	V _{CC} to GND	-	5.5	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ
Three-State Leakage Current	loz	V _{IL} or V _{IH}	-	5.5	-	-	±0.5	-	±5.0	-	±10	μА

NOTE:

2. For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
An, Bn	1.1
OEA, OEB	0.6

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360µA max at 25°C.

CD54HC243, CD74HC243, CD54HCT243, CD74HCT243

Switching Specifications Input t_r , $t_f = 6ns$

		TEST		25	°С	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES					•			•
Propagation Delay Data	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	90	115	135	ns
to Outputs			4.5	-	18	23	27	ns
		C _L = 15pF	5	7	-	-	-	ns
		CL = 50pF	6	-	15	20	23	ns
Output High-Z, to High Level	t _{PZL} , t _{PZH}	C _L = 50pF	2	-	150	190	225	ns
to Low Level		CL = 50pF	4.5	-	30	38	45	ns
		CL = 15pF	5	12	-	-	-	ns
		CL = 50pF	6	-	26	33	38	ns
Output High Level,	t _{PHZ} , t _{PLZ}	C _L = 50pF	2	-	150	190	225	ns
Output Low Level to High-Z		CL = 50pF	4.5	-	30	38	45	ns
		CL = 15pF	5	12	-	-	-	ns
		CL = 50pF	6	-	26	33	38	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	2	-	60	75	90	ns
			4.5	-	12	15	18	ns
			6	-	10	13	15	ns
Input Capacitance	Cl	-	-	-	10	10	10	pF
Three-State Output Capacitance	c _O	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	80	-	-	-	pF
HCT TYPES		•						•
Propagation Delay Data to	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	22	28	33	ns
Outputs		C _L = 15pF	5	9	-	-	-	ns
Output High-Z to High Level	t _{PZH} , t _{PZL}	C _L = 50pF	4.5	-	34	43	51	ns
to Low Level		C _L = 15pF	5	14	-	-	-	ns
Output High Level,	t _{PHZ} , t _{PLZ}	C _L = 50pF	4.5	-	35	44	53	ns
Output Low Level to High-Z		C _L = 15pF	5	14	-	-	-	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	12	15	18	ns
Input Capacitance	Cl	-	-	-	10	10	10	pF
Three-State Output Capacitance	CO	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	91	-	-	-	pF

^{3.} $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per channel.

^{4.} $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where $f_i = Input$ Frequency, $f_O = Output$ Frequency, $C_L = Output$ Load Capacitance, $V_{CC} = Supply$ Voltage.

Test Circuits and Waveforms

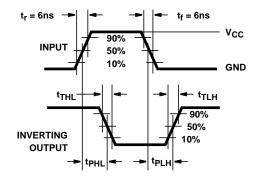


FIGURE 1. HC AND HCT TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC

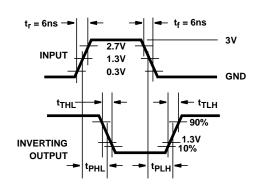


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

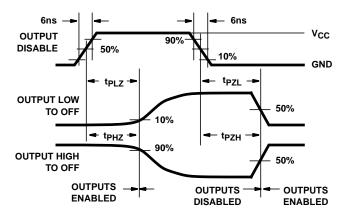


FIGURE 3. HC THREE-STATE PROPAGATION DELAY WAVEFORM

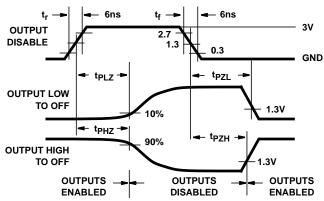
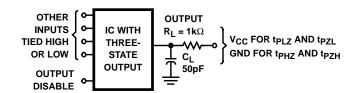


FIGURE 4. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 5. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT





28-Nov-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
8409001CA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8409001CA CD54HC243F3A	Samples
CD54HC243F	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HC243F	Samples
CD54HC243F3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8409001CA CD54HC243F3A	Sample
CD54HCT243F3A	NRND	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HCT243F3A	
CD74HC243E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC243E	Sample
CD74HC243EE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC243E	Sample
CD74HC243M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC243M	Sample
CD74HC243M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC243M	Sample
CD74HC243M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC243M	Sample
CD74HC243MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC243M	Sample
CD74HC243MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC243M	Sample
CD74HCT243E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT243E	Sample
CD74HCT243EE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT243E	Sample
CD74HCT243M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT243M	Sample
CD74HCT243MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT243M	Sample

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

PACKAGE OPTION ADDENDUM



28-Nov-2015

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD54HC243, CD54HCT243, CD74HC243, CD74HCT243:

Catalog: CD74HC243, CD74HCT243

Military: CD54HC243, CD54HCT243

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product



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PACKAGE OPTION ADDENDUM

28-Nov-2015

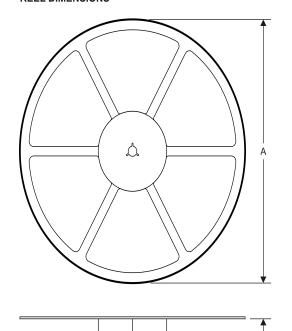
• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

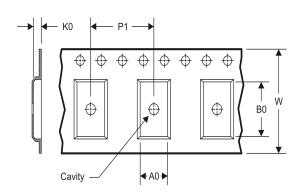
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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



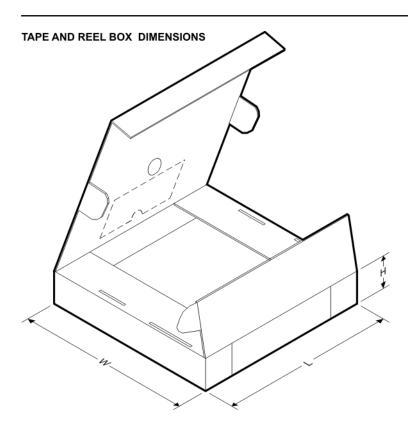
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC243M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC243MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC243M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HC243MT	SOIC	D	14	250	367.0	367.0	38.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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